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RF Micro Devices(R) Expands Industry-Leading PowerSmart(R) Product Family

BARCELONA, Spain, Feb. 28, 2012 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced the expansion of the Company's family of PowerSmart® power platforms to include multiple new 3G and 4G LTE PowerSmart product variants. RFMD's PowerSmart power platforms are at the forefront of the technology shift to converged front ends in multimode, multi-band applications, including smartphones, tablets, and other data-centric mobile broadband devices.

RFMD's newest PowerSmart power platforms include PowerSmart 4G, a converged multimode multi-band power platform capable of up to 12 bands of 4G LTE, 3G and 2G. RFMD's PowerSmart 4G is specifically designed for 4G LTE operation and expands upon RFMD's first-generation PowerSmart power platform by adding three additional bands of 3G or 4G LTE coverage. PowerSmart 4G also includes all necessary switch and signal conditioning functionality in a compact reference design, providing smartphone manufacturers a single scalable source for the entire front end.

RFMD's expanded PowerSmart product family also includes a new power platform optimized for emerging 3G entry (3Ge) applications and capable of multimode multi-band coverage of up to seven bands of 3G or 2G. Similar to PowerSmart 4G, RFMD's PowerSmart power platform for emerging 3Ge applications includes all necessary switch and signal conditioning functionality in a compact reference design.

In addition to the 4G and 3Ge power platforms, RFMD is expanding the PowerSmart product family to include multiple 3G and 4G discrete power amplifiers (PAs). The discrete PAs can be placed optionally with any RFMD PowerSmart power platform to achieve additional band or mode coverage. Architected in tandem with the RF Configurable Power Core™ in each PowerSmart power platform, these discrete PAs can deliver significantly improved PA efficiency at backed-off power.

Eric Creviston, president of RFMD's Cellular Products Group (CPG), said, "As the world's only truly converged solution with single-die multimode performance, RFMD's PowerSmart is positioned to drive the cellular wide area network (WAN) experience across a broad range of mobile devices, including tablets, notebooks, ultra-books, e-readers and next-generation in-vehicle networking. RFMD is delivering the industry's most innovative converged front ends for multimode multi-band applications, and we expect these new products to support multiple cellular handset and smartphone manufacturers this calendar year."

RFMD offers a broad portfolio of 3G and 4G LTE solutions in single-mode and converged architectures to ensure compatibility with leading chipset providers and enable global platform manufacturing. RFMD's 3G and 4G LTE product portfolio reduces the thermal impact of data usage in smartphones while enabling increased battery life during data-centric applications, such as web surfing, video calls and internet radio services.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking

statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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